


APPLICATION DATA SHEET

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Title of Invention	[HIGH-K TUNNELING DIELECTRIC FOR READ ONLY MEMORY DEVICE AND FABRICATION METHOD THEREOF]	
Application Type : regular, utility Attorney Docket Number : 9946-US-PA-1		
Correspondence address: Customer Number: 31561 		
Continuing Data: This is a Division of US application number 10248179, filed 2002-12-24 , now pending.		
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